



BIPOLAR ANALOG INTEGRATED CIRCUIT $\mu PC8172TB$

SILICON MMIC 2.5 GHz FREQUENCY UP-CONVERTER FOR WIRELESS TRANSCEIVER

DESCRIPTION

The μ PC8172TB is a silicon monolithic integrated circuit designed as frequency up-converter for wireless transceiver transmitter stage.

This IC is as same circuit current as conventional μ PC8106TB, but operates at higher frequency, higher gain and lower distortion. Consequently this IC is suitable for mobile communications.

FEATURES

- Recommended operating frequency : fRFout = 0.8 to 2.5 GHz
- Higher IP3

- : CG = 9.5 dB TYP., OIP₃ = +7.5 dBm TYP. @ f_{RFout} = 0.9 GHz
- High-density surface mounting
- : 6-pin super minimold package
- Supply voltage
 - : Vcc = 2.7 to 3.3 V

APPLICATIONS

- PCS1900M
- 2.4 GHz band transmitter/receiver system (wireless LAN etc.)

ORDERING INFORMATION

Part Number	Package	Marking	Supplying Form
μPC8172TB-E3	6-pin super minimold	СЗА	Embossed tape 8 mm wide.Pin 1, 2, 3 face the tape perforation side.Qty 3 kpcs/reel.

Remark To order evaluation samples, please contact your nearby sales office. (Part number for sample order: μ PC8172TB-A)

Caution Electro-static sensitive devices

PIN CONNECTIONS



Pin Name	
IFinput	
GND	
LOinput	
PS	
Vcc	
RFoutput	
	IFinput GND LOinput PS Vcc

SERIES PRODUCTS (T_A = +25°C, V_{CC} = V_{RFout} = 3.0 V, Z_S = Z_L = 50 Ω)

Part Number	lcc	fRFout		CG (dB)	
Fait Number	(mA)	(GHz)	@RF 0.9 GHz ^{Note}	@RF 1.9 GHz	@RF 2.4 GHz
μPC8172TB	9	0.8 to 2.5	9.5	8.5	8.0
μPC8106TB	9	0.4 to 2.0	9	7	-
μPC8109TB	5	0.4 to.2.0	6	4	-
μPC8163TB	16.5	0.8 to 2.0	9	5.5	-

Part Number		Po(sat) (dBm)			OIP₃ (dBm)	
Part Number	@RF 0.9 GHz ^{Note}	@RF 1.9 GHz	@RF 2.4 GHz	@RF 0.9 GHz ^{Note}	@RF 1.9 GHz	@RF 2.4 GHz
μPC8172TB	+0.5	0	-0.5	+7.5	+6.0	+4.0
μPC8106TB	-2	-4	-	+5.5	+2.0	-
μPC8109TB	-5.5	-7.5		+1.5	-1.0	_
μPC8163TB	+0.5	-2	-	+9.5	+6.0	-

Note $f_{RFout} = 0.83 \text{ GHz} @ \mu \text{PC8163TB}$

Remark Typical performance. Please refer to **ELECTRICAL CHARACTERISTICS** in detail. To know the associated product, please refer to each latest data sheet.

BLOCK DIAGRAM (FOR THE μPC8172TB)



SYSTEM APPLICATION EXAMPLES (SCHEMATICS OF IC LOCATION IN THE SYSTEM)



Wireless Transceiver

To know the associated products, please refer to each latest data sheet.

CONTENTS

1.	PIN EXPLANATION	5
2.	ABSOLUTE MAXIMUM RATINGS	6
3.	RECOMMENDED OPERATING CONDITIONS	6
4.	ELECTRICAL CHARACTERISTICS	6
5.	OTHER CHARACTERISTICS, FOR REFERENCE PURPOSES ONLY	7
6.	TEST CIRCUIT	8 9
7.	TYPICAL CHARACTERISTICS	12
8.	PACKAGE DIMENSIONS	24
9.	NOTE ON CORRECT USE	25
10.	RECOMMENDED SOLDERING CONDITIONS	25

1. PIN EXPLANATION

Pin No.	Pin Name	Applied Voltage (V)	Pin Voltage (V) ^{Note}	Function and Explanation	Equivalent Circuit
1	IFinput	_	1.4	This pin is IF input to double bal- anced mixer (DBM). The input is designed as high impedance. The circuit contributes to sup- press spurious signal. Also this symmetrical circuit can keep specified performance insensitive to process-condition distribution. For above reason, double bal- anced mixer is adopted.	
2	GND	GND	_	GND pin. Ground pattern on the board should be formed as wide as possible. Track Length should be kept as short as possible to minimize ground impedance.	
3	LOinput	_	2.3	Local input pin. Recommendable input level is –10 to 0 dBm.	
5	Vcc	2.7 to 3.3	_	Supply voltage pin.	
6	RFoutput	Same bias as Vcc through external inductor	-	This pin is RF output from DBM. This pin is designed as open collector. Due to the high imped- ance output, this pin should be externally equipped with LC matching circuit to next stage.	
4	PS	Vcc/GND		Power save control pin. Bias controls operation as follows.Pin biasControlVccOperationGNDPower Save	

Note Each pin voltage is measured with $V_{CC} = V_{PS} = V_{RFout} = 3.0 \text{ V}.$

Q

★ 2. ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Rating	Unit
Supply Voltage	Vcc	T _A = +25°C	3.6	V
PS pin Input Voltage	Vps	$T_A = +25^{\circ}C$	3.6	V
Power Dissipation of Package	PD	Mounted on double-side copperciad $50 \times 50 \times 1.6$ mm epoxy glass PWB (T _A = +85°C)	270	mW
Operating Ambient Temperature	TA		-40 to +85	°C
Storage Temperature	Tstg		-55 to +150	°C
Input Power	Pin		+10	dBm

3. RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Supply Voltage	Vcc	The same voltage should be applied to pin 5 and 6	2.7	3.0	3.3	V
Operating Ambient Temperature	TA		-40	+25	+85	°C
Local Input Level	P_{LOin}	$Z_s = 50 \Omega$ (without matching)	-10	-5	0	dBm
RF Output Frequency	fRFout	With external matching circuit	0.8	-	2.5	GHz
IF Input Frequency	fıFin		50	_	400	MHz

4. ELECTRICAL CHARACTERISTICS

(TA = +25°C, Vcc = VRFout = 3.0 V, fiFin = 240 MHz, PLOin = -5 dBm, and VPs ≥ 2.7 V unless otherwise specified)

Parameter	Symbol	Test Conditions ^{№te}	MIN.	TYP.	MAX.	Unit
Circuit Current	lcc	No Signal	5.5	9.0	13	mA
Circuit Current In Power Save Mode	Icc(PS)	V _{PS} = 0 V	_	_	2	μA
Conversion Gain	CG1	frFout = 0.9 GHz, PIFin = -30 dBm	6.5	9.5	12.5	dB
	CG2	$f_{RFout} = 1.9 \text{ GHz}, P_{IFin} = -30 \text{ dBm}$	5.5	8.5	11.5	dB
	CG3	$f_{RFout} = 2.4 \text{ GHz}, P_{IFin} = -30 \text{ dBm}$	5	8.0	11.0	dB
Saturated RF Output Power	Po(sat)1	$f_{RFout} = 0.9 \text{ GHz}, P_{IFin} = 0 \text{ dBm}$	-2.5	+0.5	-	dBm
	Po(sat)2	f _{RFout} = 1.9 GHz, P _{IFin} = 0 dBm	-3.5	0	-	dBm
	Po(sat)3	$f_{RFout} = 2.4 \text{ GHz}, P_{IFin} = 0 \text{ dBm}$	-4	-0.5	Ι	dBm

Note fRFout < fLoin @ fRFout = 0.9 GHz

fLoin < fRFout @ fRFout = 1.9 GHz/2.4 GHz

5. OTHER CHARACTERISTICS, FOR REFERENCE PURPOSES ONLY

(TA = +25°C, Vcc = VRFout = 3.0 V, PLOin = -5 dBm, and VPs \ge 2.7 V unless otherwise specified)

Parame	ter	Symbol	Test Condition	1S ^{Note}	Data	Unit
Output Third-Order	Distortion	OIP₃1	frFout = 0.9 GHz		+7.5	dBm
Intercept Point	ntercept Point	OIP ₃ 2	frFout = 1.9 GHz	$f_{IFin}1 = 240 \text{ MHz}$ $f_{IFin}2 = 241 \text{ MHz}$	+6.0	dBm
	OIP₃3	frFout = 2.4 GHz		+4.0	dBm	
Input Third-Order D	listortion	IIP₃1	frFout = 0.9 GHz		-2.0	dBm
Intercept Point		IIP32	frFout = 1.9 GHz	$f_{IFin}1 = 240 \text{ MHz}$ $f_{IFin}2 = 241 \text{ MHz}$	-2.5	dBm
		IIP₃3	frFout = 2.4 GHz		-4.0	dBm
SSB Noise Figure		SSB•NF1	freFout = 0.9 GHz, fifin = 240 MHz		9.5	dB
		SSB•NF2	frFout = 1.9 GHz, fIFin = 240 MHz		10.4	dB
			f _{RFout} = 2.4 GHz, f _{IFin} = 240 MHz		10.6	dB
Power Save	Rise time	TPS(rise)	VPS: $\text{GND} \rightarrow \text{Vcc}$		1	μs
Response Time	Fall time	TPS(fall)	Vps: Vcc \rightarrow GND		1.5	μs

Note fRFout < fLOin @ fRFout = 0.9 GHz

 $f_{LOin} < f_{RFout} @ f_{RFout} = 1.9 GHz/2.4 GHz$

6. TEST CIRCUIT

★ 6.1 TEST CIRCUIT 1 (fRFout = 900 MHz)



EXAMPLE OF TEST CIRCUIT 1 ASSEMBLED ON EVALUATION BOARD



COMPONENT LIST

Form	Symbol	Value
Chip capacitor	C1, C2, C3	100 pF
	C4	1 000 pF
	C5, C6	1 <i>µ</i> F
	C7	68 pF
	C8	1 pF
Chip inductor	L	10 nH ^{∾œ}

- (*1) $35 \times 42 \times 0.4$ mm polyimide board, double-sided copper clad
- (*2) Ground pattern on rear of the board
- (*3) Solder plated patterns
- (*4) $\circ \circ \bigcirc$: Through holes

Note 10 nH: LL1608-FH10N (TOKO Co., Ltd.)

★

6.2 TEST CIRCUIT 2 (fRFout = 1.9 GHz)



EXAMPLE OF TEST CIRCUIT 2 ASSEMBLED ON EVALUATION BOARD



COMPONENT LIST

Form	Symbol	Value	(
Chip capacitor	C1, C2, C3	100 pF	(
	C4	1 000 pF	(
	C5, C6	1 <i>µ</i> F	(
	C7	30 pF	
	C ₈	2.75 pF	
Chip inductor	L	470 nH ^{№ote}	

Note 470 nH: LL2012-FR47 (TOKO Co., Ltd.)

- (*1) $35 \times 42 \times 0.4$ mm polyimide board, double-sided copper clad
- (*2) Ground pattern on rear of the board
- (*3) Solder plated patterns
- (*4) •••: Through holes

★ 6.3 TEST CIRCUIT 3 (fRFout = 2.4 GHz)



EXAMPLE OF TEST CIRCUIT 3 ASSEMBLED ON EVALUATION BOARD



COMPONENT LIST

Form	Symbol	Value	
Chip capacitor	C1, C2, C3	100 pF	
	C4	1 000 pF	
	C5, C6	1 <i>µ</i> F	
	C7	10 pF	
	C ₈	1.75 pF	
Chip inductor	L	470 nH ^{∾ote}	

^(*1) $35 \times 42 \times 0.4$ mm polyimide board, double-sided copper clad

- (*2) Ground pattern on rear of the board
- (*3) Solder plated patterns
- (*4) ••• : Through holes

Note 470 nH: LL2012-FR47 (TOKO Co., Ltd.)

Caution The test circuits and board pattern on data sheet are for performance evaluation use only (They are not recommended circuits). In the case of actual design-in, matching circuit should be determined using S-parameter of desired frequency in accordance to actual mounting pattern.

★ 7. TYPICAL CHARACTERISTICS (Unless otherwise specified, TA = +25°C, Vcc = VRFout)



*

S-PARAMETERS FOR EACH PORT (Vcc = VPs = VRFout = 3.0 V) (The parameters are monitored at DUT pins)



★ S-PARAMETERS FOR MATCHED RF OUTPUT (Vcc = VPS = VRFout = 3.0 V) –ON EVALUATION BOARD– (S22 data are monitored at RF connector on board)



★ S-PARAMETERS FOR MATCHED RF OUTPUT (Vcc = VPS = VRFout = 3.0 V) -ON EVALUATION BOARD-(S22 data are monitored at RF connector on board)









μPC8172TB





μPC8172TB







Remark The graphs indicate nominal characteristics.

★ 8. PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



9. NOTE ON CORRECT USE

- (1) Observe precautions for handling because of electrostatic sensitive devices.
- (2) Form a ground pattern as wide as possible to minimize ground impedance (to prevent undesired oscillation).
- (3) Connect a bypass capacitor (example: 1 000 pF) to the Vcc pin.
- (4) Connect a matching circuit to the RF output pin.
- (5) The DC cut capacitor must be each attached to the input and output pins.

10. RECOMMENDED SOLDERING CONDITIONS

This product should be soldered under the following recommended conditions.

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared Reflow	Package peak temperature: 235°C or below Time: 30 seconds or less (at 210°C) Count: 3, Exposure limit: None ^{Note}	IR35-00-3
VPS	Package peak temperature: 215°C or below Time: 40 seconds or less (at 200°C) Count: 3, Exposure limit: None ^{Note}	VP15-00-3
Wave Soldering	Soldering bath temperature: 260°C or below Time: 10 seconds or less Count: 1, Exposure limit: None ^{Note}	WS60-00-1
Partial Heating	Pin temperature: 300°C Time: 3 seconds or less (per side of device) Exposure limit: None ^{Note}	_

Note After opening the dry pack, keep it in a place below 25°C and 65% RH for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

NOTICE

- 1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. California Eastern Laboratories and Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- 2. California Eastern Laboratories has used reasonable care in preparing the information included in this document, but California Eastern Laboratories does not warrant that such information is error free. California Eastern Laboratories and Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 3. California Eastern Laboratories and Renesas Electronics do not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics products or technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of California Eastern Laboratories or Renesas Electronics or others.
- 4. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part. California Eastern Laboratories and Renesas Electronics assume no responsibility for any losses incurred by you or third parties arising from such alteration, modification, copy or otherwise misappropriation of Renesas Electronics product.
- 5. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below. "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots etc. "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; and safety equipment etc. Renesas Electronics products are neither intended nor authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems, surgical implantations etc.), or may cause serious property damages (nuclear reactor control systems, military equipment etc.). You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application for which it is not intended. California Eastern Laboratories and Renesas Electronics product for which the product is not intended by California Eastern Laboratories or Renesas Electronics.
- 6. You should use the Renesas Electronics products described in this document within the range specified by California Eastern Laboratories, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. California Eastern Laboratories shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 7. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or systems manufactured by you.
- 8. Please contact a California Eastern Laboratories sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. California Eastern Laboratories and Renesas Electronics assume no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 9. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You should not use Renesas Electronics products or technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. When exporting the Renesas Electronics products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations.
- 10. It is the responsibility of the buyer or distributor of California Eastern Laboratories, who distributes, disposes of, or otherwise places the Renesas Electronics product with a third party, to notify such third party in advance of the contents and conditions set forth in this document, California Eastern Laboratories and Renesas Electronics assume no responsibility for any losses incurred by you or third parties as a result of unauthorized use of Renesas Electronics products.
- This document may not be reproduced or duplicated in any form, in whole or in part, without prior written consent of California Eastern Laboratories.
 Please contact a California Eastern Laboratories sales office if you have any questions regarding the information contained in this document or Renesas
- Electronics products, or if you have any other inquiries.

NOTE 1: "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries. **NOTE 2:** "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics. **NOTE 3:** Products and product information are subject to change without notice.

CEL Headquarters • 4590 Patrick Henry Drive, Santa Clara, CA 95054 • Phone (408) 919-2500 • www.cel.com

For a complete list of sales offices, representatives and distributors, Please visit our website: www.cel.com/contactus